# NSN 5961-01-012-6679

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-012-6679

Inclosure Material:

Metal

**Overall Length:** 

0.300 inches

# **Overall Diameter:**

0.830 inches

# **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

**Mounting Method:** 

# Unthreaded hole

Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.6 emitter to base voltage, dc

## **Current Rating Per Characteristic:**

Between 7.50 amperes source cutoff current and 20.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

200.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

## Unit Of Measure:

---

```
Demilitarization:
```

No

Fiig:

A110a0